

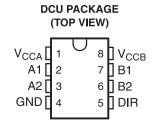
DUAL-BIT DUAL-SUPPLY BUS TRANSCEIVER WITH CONFIGURABLE VOLTAGE TRANSLATION AND 3-STATE OUTPUTS

Check for Samples: SN74LVC2T45-Q1

FEATURES

- Qualified for Automotive Applications
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, Both Ports Are in the High-Impedance State
- DIR Input Circuit Referenced to V_{CCA}
- Low Power Consumption, 10-μA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Partial-Power-Down Mode Operation
- Max Data Rates
 - 420 Mbps (3.3-V to 5-V Translation)

- 210 Mbps (Translate to 3.3 V)
- 140 Mbps (Translate to 2.5 V)
- 75 Mbps (Translate to 1.8 V)



DESCRIPTION/ORDERING INFORMATION

This dual-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

The SN74LVC2T45-Q1 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input activate either the B-port outputs or the A-port outputs. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports always is active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ} .

The SN74LVC2T45-Q1 is designed so that the DIR input circuit is supplied by V_{CCA}.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, both ports are in the high-impedance state.

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

ORDERING INFORMATION

T _A	PACKAG	E ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	VSSOP - DCU	Reel of 3000	SN74LVC2T45QDCURQ1	CAWR

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

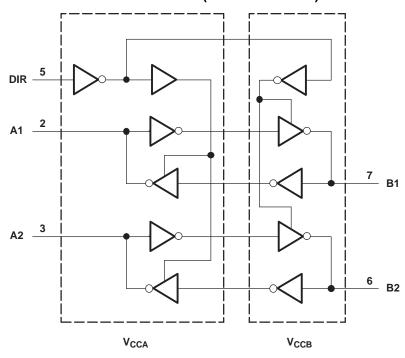


FUNCTION TABLE⁽¹⁾ (EACH TRANSCEIVER)

INPUT DIR	OPERATION
L	B data to A bus
Н	A data to B bus

(1) Input circuits of the data I/Os always are active.

LOGIC DIAGRAM (POSITIVE LOGIC)





ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA}	Supply voltage range	-0.5	6.5	V	
VI	Input voltage range ⁽²⁾	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high-impedance or power-or	off state ⁽²⁾	-0.5	6.5	V
.,	Valence and a special to any system time that high an law state (2) (3)	A port	-0.5	V _{CCA} + 0.5	
Vo	Voltage range applied to any output in the high or low state (2) (3)	B port	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
lok	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current	·		±50	mA
	Continuous current through V _{CC} or GND			±100	mA
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCU package		329.4	°C/W
T _{stg}	Storage temperature range	·	-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

²⁾ The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the recommended operating conditions table.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

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RECOMMENDED OPERATING CONDITIONS(1) (2) (3)

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V_{CCA}	Cupply voltogo				1.65	5.5	V
V_{CCB}	Supply voltage				1.65	5.5	V
			1.65 V to 1.95 V		$V_{\rm CCI} \times 0.65$		
V	High-level	Data inputs ⁽⁴⁾	2.3 V to 2.7 V		1.7		V
V_{IH}	input voltage	Data inputs	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		V _{CCI} × 0.7		
			1.65 V to 1.95 V			V _{CCI} × 0.35	
	Low-level	D-1- :(4)	2.3 V to 2.7 V			0.7	
V_{IL}	input voltage	Data inputs ⁽⁴⁾	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCI} \times 0.3$	
			1.65 V to 1.95 V		V _{CCA} × 0.65		
	High-level	DIR	2.3 V to 2.7 V		1.7		.,
V_{IH}	input voltage	(referenced to V _{CCA}) ⁽⁵⁾	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		$V_{CCA} \times 0.7$		
			1.65 V to 1.95 V			V _{CCA} × 0.35	
.,	Low-level Input voltage	DIR	2.3 V to 2.7 V			0.7	.,
V_{IL}		(referenced to V _{CCA}) ⁽⁵⁾	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCA} \times 0.3$	
VI	Input voltage				0	5.5	V
Vo	Output voltage				0	V _{CCO}	V
				1.65 V to 1.95 V		-4	
				2.3 V to 2.7 V		-8	_
I _{OH}	High-level output cu	rrent		3 V to 3.6 V		-24	mA
				4.5 V to 5.5 V		-32	
				1.65 V to 1.95 V		4	
				2.3 V to 2.7 V		8	
I_{OL}	Low-level output cur	rent		3 V to 3.6 V		24	mA
				4.5 V to 5.5 V		32	
			1.65 V to 1.95 V			20	
			2.3 V to 2.7 V			20	
Δt/Δν	Input transition rise or fall rate	Data inputs	3 V to 3.6 V			10	ns/V
	nse ui iaii iale		4.5 V to 5.5 V			5	
		Control input	1.65 V to 5.5 V			5	
T _A	Operating free-air te	mperature			-40	125	°C

 ⁽¹⁾ V_{CCI} is the V_{CC} associated with the input port.
 (2) V_{CCO} is the V_{CC} associated with the output port.
 (3) All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.
 (4) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} x 0.7 V, V_{IL} max = V_{CCI} x 0.3 V.
 (5) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCA} x 0.7 V, V_{IL} max = V_{CCA} x 0.3 V.



ELECTRICAL CHARACTERISTICS(1) (2)

over recommended operating free-air temperature range (unless otherwise noted)

	METER	TEST CONDITI	ONS	V.	V-	Т	A = 25°	С	-40°C to 12	25°C	UNIT
TANAMETER		TEST CONDITI	ONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNII
		$I_{OH} = -100 \ \mu A$		1.65 V to 4.5 V	1.65 V to 4.5 V				V _{CCO} - 0.1		
		$I_{OH} = -4 \text{ mA}$		1.65 V	1.65 V				1.2		
V_{OH}		$I_{OH} = -8 \text{ mA}$	$V_I = V_{IH}$	2.3 V	2.3 V				1.9		V
		$I_{OH} = -24 \text{ mA}$		3 V	3 V				2.4		
		$I_{OH} = -32 \text{ mA}$		4.5 V	4.5 V				3.8		
		$I_{OL} = 100 \ \mu A$		1.65 V to 4.5 V	1.65 V to 4.5 V					0.1	
		$I_{OL} = 4 \text{ mA}$		1.65 V	1.65 V					0.45	
V_{OL}		$I_{OL} = 8 \text{ mA}$	$V_I = V_{IL}$	2.3 V	2.3 V					0.3	V
		$I_{OL} = 24 \text{ mA}$		3 V	3 V					0.55	
		I_{OL} = 32 mA		4.5 V	4.5 V					0.55	
l _l	DIR	$V_I = V_{CCA}$ or GND		1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±2	μΑ
	A port	\\ or\\ - 0 to 5 5 \\	,	0 V	0 to 5.5 V			±1		±9	
l _{off}	B port	$V_{\rm I}$ or $V_{\rm O} = 0$ to 5.5 V		0 to 5.5 V	0 V			±1		±9	μА
I _{OZ}	A or B port	$V_O = V_{CCO}$ or GND		1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±9	μА
				1.65 V to 5.5 V	1.65 V to 5.5 V					4	
I _{CCA}		$V_I = V_{CCI}$ or GND, I	l _O = 0	5 V	0 V					2	μΑ
				0 V	5 V					-12	
				1.65 V to 5.5 V	1.65 V to 5.5 V					4	
I _{CCB}		$V_I = V_{CCI}$ or GND, I	I _O = 0	5 V	0 V					-12	μΑ
				0 V	5 V					2	
I _{CCA} +	I _{CCB}	$V_I = V_{CCI}$ or GND, I	l _O = 0	1.65 V to 5.5 V	1.65 V to 5.5 V					4	μΑ
A. I.	A port	One A port at V _{CCA} DIR at V _{CCA} , B port = open	– 0.6 V,	0.74.557	0.74.55.7					50	٨
ΔI _{CCA}	DIR	DIR at $V_{CCA} - 0.6 V$ B port = open, A port at V_{CCA} or GN		3 V to 5.5 V	3 V to 5.5 V					50	μА
ΔI _{CCB}	B port	One B port at V _{CCB} - DIR at GND, A port		3 V to 5.5 V	3 V to 5.5 V					50	μΑ
Cı	DIR	$V_I = V_{CCA}$ or GND		3.3 V	3.3 V		2.5				pF
C _{io}	A or B port	$V_O = V_{CCA/B}$ or GND		3.3 V	3.3 V		6				pF

 $[\]begin{array}{ll} \hbox{(1)} & V_{CCO} \text{ is the } V_{CC} \text{ associated with the output port.} \\ \hbox{(2)} & V_{CCI} \text{ is the } V_{CC} \text{ associated with the input port.} \\ \end{array}$

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V _{CCB} = 1.8 V ±0.15 V		V _{CCB} = 2.5 V ±0.2 V		V _{CCB} = 3.3 V ±0.3 V		V _{CCB} = 5 V ±0.5 V		UNIT
	(INPUT)		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α	В	3	21.7	2.2	14.3	1.7	12.3	1.4	11.2	ne
t _{PHL}		Ь	2.8	28.3	2.2	12.5	1.8	11.1	1.7	11	ns
t _{PLH}	В	А	3	21.7	2.3	20	2.1	19.5	1.9	19.1	20
t _{PHL}	ь	A	2.8	18.3	2.1	16.9	2	16.6	1.8	16.2	ns
t _{PHZ}	DIR	А	10.6	34.9	10.3	34.5	10.5	34.5	10.7	33.3	ns
t _{PLZ}	DIK	A	7.3	23.7	7.5	23.6	7.5	23.5	7	23.4	113
t _{PHZ}	DIR	В	10	31.9	8.4	18.9	6.5	15.3	4.1	12.6	ne
t _{PLZ}	DIK	ь	6.5	23.5	7.2	16.6	4.3	13.7	2.1	11.1	ns
t _{PZH} ⁽¹⁾	DIR	А		45.2		36.6		33.2		30.2	20
t _{PZL} ⁽¹⁾	אוט	A		50.2		35.8		31.9		28.8	ns
t _{PZH} (1)	DIR	В		45.4		37.9		35.8		34.6	20
t _{PZL} ⁽¹⁾	ЫK	Б		53.2		47		45.6		44.3	ns

⁽¹⁾ The enable time is a calculated value, derived using the formula shown in the enable times section.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, V_{CCA} = 2.5 V ± 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (CUITOUT)	V _{CCB} = 1.8 V ±0.15 V		V _{CCB} = 2.5 V ±0.2 V		V _{CCB} = 3.3 V ±0.3 V		V _{CCB} = 5 V ±0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	۸	В	2.3	20	1.5	12.5	1.3	10.4	1.1	9.1	20
t _{PHL}	Α	ь	2.1	16.9	1.4	11.5	1.3	9.4	0.9	8.6	ns
t _{PLH}	В	^	2.2	14.3	1.5	12.5	1.4	12	1	11.5	20
t _{PHL}	В	Α	2.2	12.5	1.4	11.5	1.3	11	0.9	10.2	ns
t _{PHZ}	DIR	А	6.6	21.1	7.1	20.8	6.8	20.8	5.2	20.5	ns
t_{PLZ}	DIK	A	5.3	16.6	5.2	16.5	4.9	16.3	4.8	16.3	113
t_{PHZ}	DIR	В	10.7	31.9	8.1	17.9	5.8	14.5	3.5	11.6	20
t_{PLZ}	DIK	Ь	7.8	22.9	6.2	15.2	3.6	12.9	1.4	11.2	ns
t _{PZH} (1)	DIB	^		37.2		27.7		24.9		21.7	20
t _{PZL} ⁽¹⁾	DIR	A		44.4		29.4		25.5		21.8	ns
t _{PZH} ⁽¹⁾	DIR	В		28.6		29		26.7		25.4	20
t _{PZL} ⁽¹⁾	אוט	В		38	·	32.3		30.2		29.1	ns

⁽¹⁾ The enable time is a calculated value, derived using the formula shown in the enable times section.

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V _{CCB} = 1.8 V ±0.15 V		V _{CCB} = 2.5 V ±0.2 V		V _{CCB} = 3.3 V ±0.3 V		V _{CCB} = 5 V ±0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α	В	2.1	19.5	1.4	12	0.7	9.6	0.7	8.4	20
t _{PHL}	A	ь	2	16.6	1.3	11	0.8	9	0.7	8	ns
t _{PLH}	В	А	1.7	12.3	1.3	10.4	0.7	9.8	0.6	9.4	20
t _{PHL}	ь	A	1.8	11.1	1.3	9.4	0.8	9	0.7	8.5	ns
t _{PHZ}	DIR	А	5	14.9	5.1	14.8	5	14.8	5	14.4	ns
t _{PLZ}	DIK	A	3.4	12.4	3.7	12.4	3.9	12.1	3.3	11.8	113
t _{PHZ}	DIR	В	11.2	31.3	8	17.7	5.8	14.4	2.9	11.4	20
t _{PLZ}	DIK	ь	9.4	21.7	5.6	15.3	4.3	12.3	1	9.6	ns
t _{PZH} ⁽¹⁾	DID	А		34		25.7		22.1		19	
t _{PZL} ⁽¹⁾	DIR	A		42.4		27.1		23.4		19.9	ns
t _{PZH} (1)	DIB	В		31.9		24.4		21.9		20.2	ns
t _{PZL} ⁽¹⁾	ЫK	DIR B		31.5		25.8		23.8		22.4	

⁽¹⁾ The enable time is a calculated value, derived using the formula shown in the enable times section.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, V_{CCA} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V _{CCB} = ±0.15		V _{CCB} = 2.5 V ±0.2 V		V _{CCB} = 3.3 V ±0.3 V		V _{CCB} = 5 V ±0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}		В	1.9	19.1	1	11.5	0.6	9.4	0.5	7.9	no
t _{PHL}	Α	В	1.8	16.2	0.9	10.2	0.7	8.5	0.5	7.5	ns
t _{PLH}	В	А	1.4	11.2	1	9.1	0.7	8.4	0.5	7.9	no
t _{PHL}	ь	A	1.7	11	0.9	8.6	0.7	8	0.5	7.5	ns
t_{PHZ}	DIR	А	2.9	12.2	2.9	11.9	2.8	11.9	2.2	11.8	ns
t_{PLZ}	DIK	A	1.4	10.9	1.3	10.7	0.7	10.7	0.7	10.6	113
t_{PHZ}	DIR	В	11.2	30.1	7.2	17.9	5.8	14.1	1.3	11.3	no
t_{PLZ}	DIK	Ь	8.4	20.9	5	15	4	11.7	1	9.6	ns
t _{PZH} ⁽¹⁾	DIR	А		32.1		24.1		20.1		18.5	no
t _{PZL} ⁽¹⁾	אוט	A		41.1		26.5		22.1		18.8	ns
t _{PZH} ⁽¹⁾	DIR	В		30		22.2		20.1		18.5	20
t _{PZL} ⁽¹⁾	אוט	В		28.4		22.1		22.4		19.3	ns

⁽¹⁾ The enable time is a calculated value, derived using the formula shown in the enable times section.



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OPERATING CHARACTERISTICS

 $T_A = 25^{\circ}C$

I - 25 (PARAMETER	TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.8 V	V _{CCA} = V _{CCB} = 2.5 V	$V_{CCA} = V_{CCB} = 3.3 \text{ V}$ TYP	V _{CCA} = V _{CCB} = 5 V	UNIT
C (1)	A-port input, B-port output	C _L = 0 pF,	3	4	4	4	~F
C _{pdA} ⁽¹⁾	B-port input, A-port output	$f = 10 \text{ MHz},$ $t_r = t_f = 1 \text{ ns}$	18	19	20	21	pF
o (1)	A-port input, B-port output	$C_L = 0 \text{ pF},$	18	19	20	21	
C _{pdB} (1)	B-port input, A-port output	$f = 10 \text{ MHz},$ $t_r = t_f = 1 \text{ ns}$	3	4	4	4	pF

⁽¹⁾ Power dissipation capacitance per transceiver



Power-Up Considerations

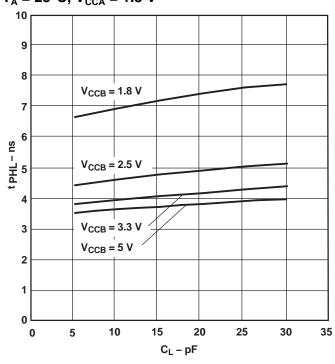
A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies. To guard against such power-up problems, take the following precautions:

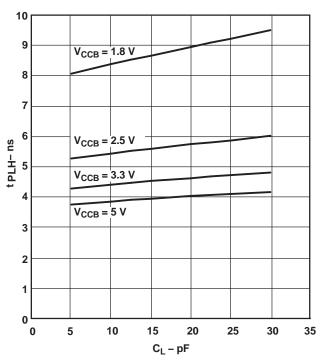
- 1. Connect ground before any supply voltage is applied.
- 2. Power up V_{CCA}.
- 3. V_{CCB} can be ramped up along with or after V_{CCA} .



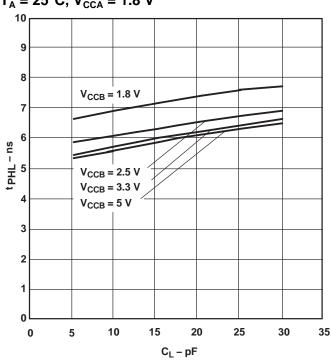
TYPICAL CHARACTERISTICS

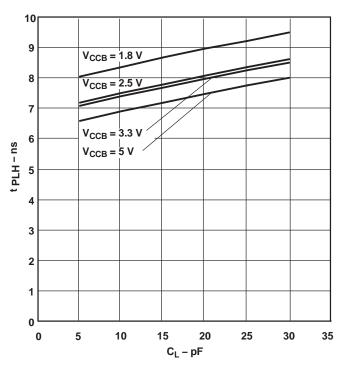
TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE T_{A} = 25°C, V_{CCA} = 1.8 V





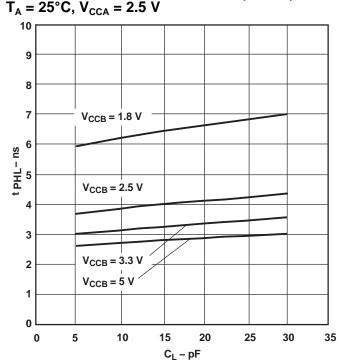
TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 1.8 V

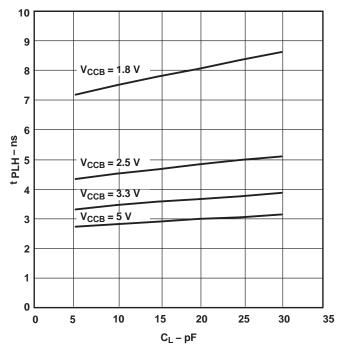






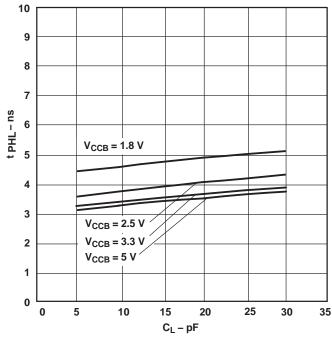
TYPICAL CHARACTERISTICS (continued) TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE

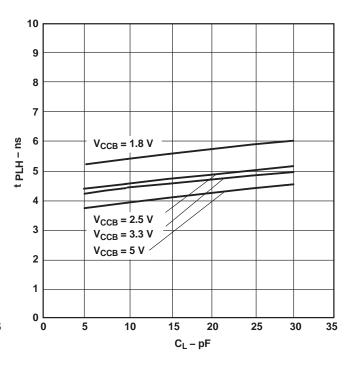




TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE

 $T_A = 25^{\circ}C$, $V_{CCA} = 2.5 \text{ V}$

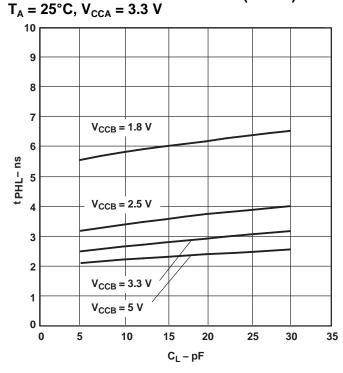


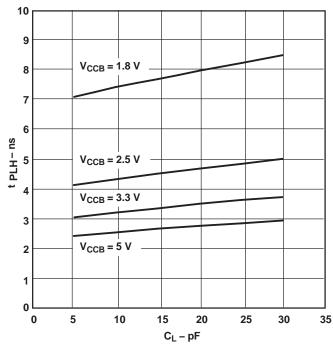




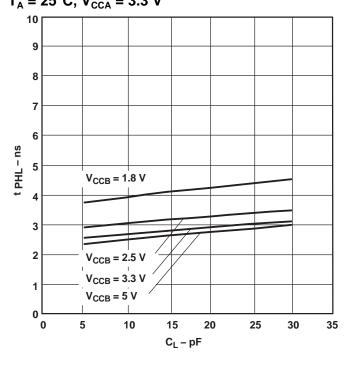


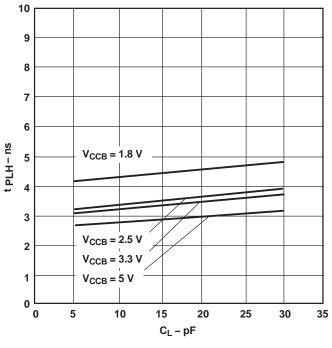
TYPICAL CHARACTERISTICS (continued) TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE





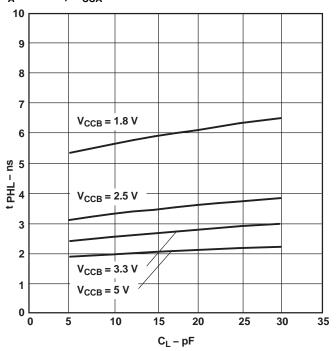
TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 3.3 V

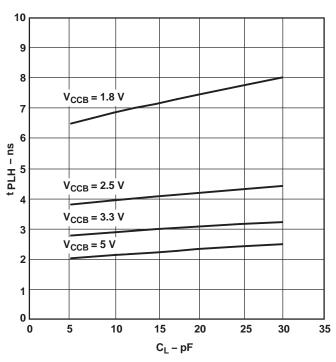




TYPICAL CHARACTERISTICS (continued) TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE

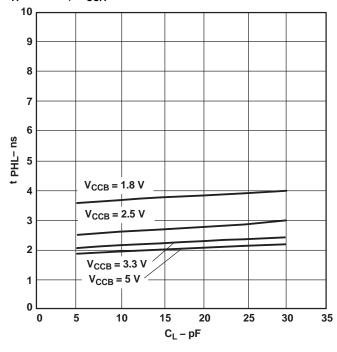
 $T_A = 25^{\circ}C, V_{CCA} = 5 V$

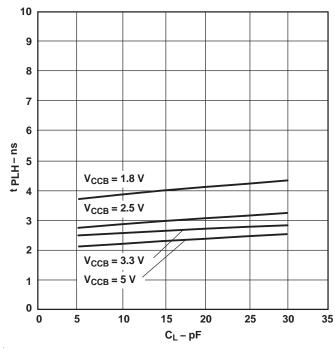




TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE

 $T_A = 25$ °C, $V_{CCA} = 5$ V

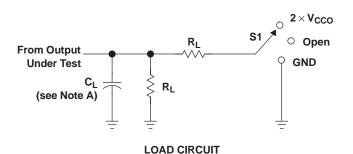




ISTRUMENTS

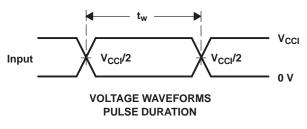
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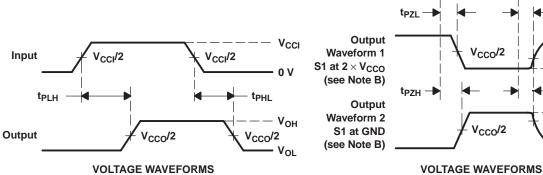
PARAMETER MEASUREMENT INFORMATION

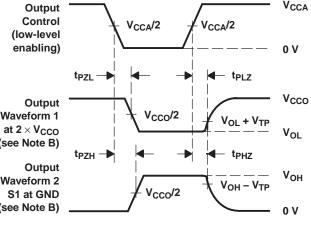


TEST	S 1
t _{pd}	Open
t _{PLZ} /t _{PZL}	$2 \times V_{CCO}$
t _{PHZ} /t _{PZH}	GND

V _{CCO}	CL	R _L	V _{TP}
1.8 V \pm 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	15 pF	2 k Ω	0.15 V
3.3 V \pm 0.3 V	15 pF	2 k Ω	0.3 V
5 V \pm 0.5 V	15 pF	2 k Ω	0.3 V







ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $dv/dt \geq 1 V/ns$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.
- V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.

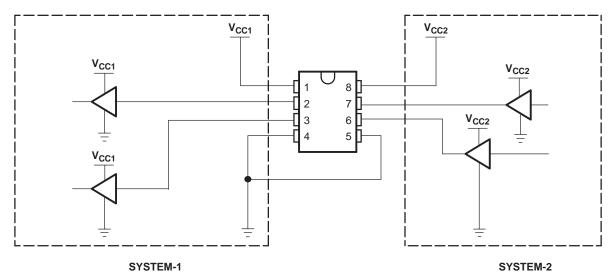
PROPAGATION DELAY TIMES

J. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

APPLICATION INFORMATION

The following shows an example of the SN74LVC2T45-Q1 being used in a unidirectional logic level-shifting application.



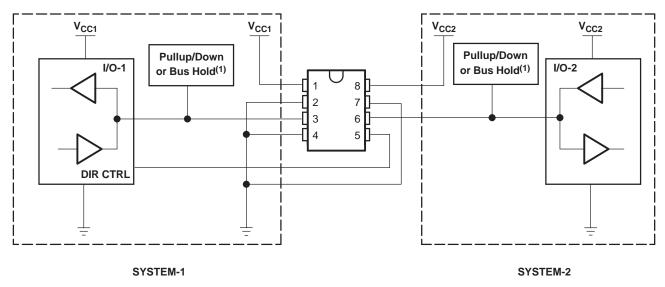
PIN	NAME	FUNCTION	DESCRIPTION
1	V _{CCA}	V _{CC1}	SYSTEM-1 supply voltage (1.65 V to 5.5 V)
2	A1	OUT1	Output level depends on V _{CC1} voltage.
3	A2	OUT2	Output level depends on V _{CC1} voltage.
4	GND	GND	Device GND
5	DIR	DIR	GND (low level) determines B-port to A-port direction.
6	B2	IN2	Input threshold value depends on V _{CC2} voltage.
7	B1	IN1	Input threshold value depends on V _{CC2} voltage.
8	V _{CCB}	V _{CC2}	SYSTEM-2 supply voltage (1.65 V to 5.5 V)

Figure 2. Unidirectional Logic Level-Shifting Application



APPLICATION INFORMATION

Figure 3 shows the SN74LVC2T45-Q1 being used in a bidirectional logic level-shifting application. Since the SN74LVC2T45-Q1 does not have an output-enable (OE) pin, the system designer should take precautions to avoid bus contention between SYSTEM-1 and SYSTEM-2 when changing directions.



The following table shows data transmission from SYSTEM-1 to SYSTEM-2 and then from SYSTEM-2 to SYSTEM-1.

STATE	DIR CTRL	I/O-1	I/O-2	DESCRIPTION
1	Н	Out	In	SYSTEM-1 data to SYSTEM-2
2	Н	Hi-Z	Hi-Z	SYSTEM-2 is getting ready to send data to SYSTEM-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on pullup or pulldown. (1)
3	L	Hi-Z	Hi-Z	DIR bit is flipped. I/O-1 and I/O-2 still are disabled. The bus-line state depends on pullup or pulldown. (1)
4	L	ln	Out	SYSTEM-2 data to SYSTEM-1

(1) SYSTEM-1 and SYSTEM-2 must use the same conditions, i.e., both pullup or both pulldown.

Figure 3. Bidirectional Logic Level-Shifting Application

Enable Times

Calculate the enable times for the SN74LVC2T45-Q1 using the following formulas:

- t_{PZH} (DIR to A) = t_{PLZ} (DIR to B) + t_{PLH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{PZI} (DIR to B) = t_{PHZ} (DIR to A) + t_{PHI} (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the SN74LVC2T45-Q1 initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.

Submit Documentation Feedback



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LVC2T45QDCURQ1	ACTIVE	VSSOP	DCU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAWR	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC2T45-Q1:



PACKAGE OPTION ADDENDUM

10-Dec-2020

Enhanced Product: SN74LVC2T45-EP

NOTE: Qualified Version Definitions:

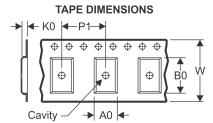
- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2T45QDCURQ1	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3

www.ti.com 3-Aug-2017



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2T45QDCURQ1	VSSOP	DCU	8	3000	202.0	201.0	28.0

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-187 variation CA.



DCU (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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